



MICROCIRCUIT DATA SHEET

MN100352-X REV 1A0

Original Creation Date: 10/30/95
 Last Update Date: 08/24/98
 Last Major Revision Date: 08/03/98

LOW POWER 8-BIT BUFFER WITH CUT-OFF DRIVERS

General Description

The F100352 contains an eight bit buffer, individual inputs (Dn), outputs (Qn), and a data output enable pin (\overline{OEN}). A Q output follows its D input when the \overline{OEN} pin is LOW. A HIGH on \overline{OEN} holds the outputs in a cut-off state. The cut-off state is designed to be more negative than a normal ECL LOW level. This allows the output emitter-followers to turn off when the termination supply is -2.0V, presenting a high impedance to the data bus. This high impedance reduces termination power and prevents loss of low state noise margin when several loads share the bus.

The F100352 outputs are designed to drive a doubly terminated 50 ohm transmission line (25 ohm load impedance). All inputs have 50K ohms pull-down resistors.

Industry Part Number

100352

NS Part Numbers

100352DMQB
 100352FMQB

Prime Die

F352

Processing

MIL-STD-883, Method 5004

Quality Conformance Inspection

MIL-STD-883, Method 5005

Subgrp Description

Temp (°C)

1	Static tests at	+25
2	Static tests at	+125
3	Static tests at	-55
4	Dynamic tests at	+25
5	Dynamic tests at	+125
6	Dynamic tests at	-55
7	Functional tests at	+25
8A	Functional tests at	+125
8B	Functional tests at	-55
9	Switching tests at	+25
10	Switching tests at	+125
11	Switching tests at	-55

Features

- Cut-off Drivers
- Drives 25 ohm load
- Low power operation
- 2000V ESD protection
- Voltage compensated operating range= -4.2V to -5.7V
- Available to industrial grade temperature range
- Available to MIL-STD-883

(Absolute Maximum Ratings)

(Note 1)

Storage Temperature (Tstg)	-65C to +150C
Maximum Junction Temperature (Tj)	
Ceramic	+175C
Plastic	+150C
Vee Pin Potential to Ground Pin	-7.0V to +0.5V
Input Voltage (DC)	Vee to +0.5V
Output Current (DC Output HIGH)	-100 mA
ESD (Note 2)	≥2000V

Note 1: Absolute maximum ratings are those values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: ESD testing conforms to MIL-STD-883, Method 3015.

Recommended Operating Conditions

Case Temperature (Tc)	
Commercial	0 C to +85 C
Industrial	-40 C to +85C
Military	-55C to +125C
Supply Voltage (Vee)	-5.7V to -4.2V

Electrical Characteristics

DC PARAMETERS

(The following conditions apply to all the following parameters, unless otherwise specified.)
DC: Vee Range: -4.2V to -5.7V, Tc= -55C to +125C, VCC=VCCA=GND

SYMBOL	PARAMETER	CONDITIONS	NOTES	PIN-NAME	MIN	MAX	UNIT	SUB-GROUPS
IIH	Input HIGH Current	VEE=-5.7V, VM=-0.87V	1, 3	Input		240	uA	1, 2
			1, 3	Input		340	uA	3
IIL	Input Low Current	VEE=-4.2V, VM=-1.83V	1, 3	INPUTS	0.5		uA	1, 2, 3
VOH	Output HIGH Voltage	VEE=-4.2/-5.7V, VIH=-0.87V, VIL=-1.83V LOADING:25 Ohms to -2.0V	1, 3	OUTPUTS	-1025	-870	mV	1, 2
			1, 3	OUTPUTS	-1085	-870	mV	3
VOL	Output LOW Voltage	Vee=-4.2V/-5.7V, VIH=-0.87V, VIL=-1.83V, \overline{OEN} =-1.83V, LOADING:25 ohms to -2.0V	1, 3	OUTPUTS	-1830	-1620	mV	1, 2
			1, 3	OUTPUTS	-1830	-1555	mV	3
		Vee= -4.2V/-5.7V, VIH=-0.87V, VIL=-1.83V, \overline{OEN} =-0.87V, LOADING: 25 ohms to -2.0V	1, 3	OUT CUTOFF VOLTAGE		-1950	mV	1, 2
			1, 3	OUT CUTOFF VOLTAGE		-1850	mV	3
VOHC	Output HIGH Voltage Corner Point High	Vee=-4.2V/-5.7V, VIH=-1.165V, VIL=-1.475V, Loading:25 Ohms to -2.0V	1, 3	OUTPUTS	-1035		mV	1, 2
			1, 3	OUTPUTS	-1085		mV	3
VOLC	Output LOW Voltage Corner Point High	Vee=-4.2V/-5.7V, VIH=-1.165V, VIL=-1.475V, \overline{OEN} =-1.475V, Loading: 25 Ohms to -2.0V	1, 3	OUTPUTS		-1610	mV	1, 2
			1, 3	OUTPUTS		-1555	mV	3
		Vee=-4.2V/-5.7V, VIH=-1.165V, VIL=-1.475V, \overline{OEN} =-1.165V, Loading: 25 ohms to -2.0V	1, 3	OUT CUTOFF VOLTAGE		-1950	mV	1, 2
			1, 3	OUT CUTOFF VOLTAGE		-1850	mV	3
VIH	Input HIGH Voltage		1, 3, 7	INPUTS	-1165	-870	mV	1, 2, 3
VIL	Input LOW Voltage		1, 3, 7	INPUTS	-1830	-1475	mV	1, 2, 3
IEE	Power Supply Current	VEE=-4.2/-4.8V	1, 3	VEE	-145	-55	mA	1, 2, 3
		VEE=-4.2/-5.7V	1, 3	VEE	-150		mA	1, 2, 3

Electrical Characteristics

AC PARAMETERS

(The following conditions apply to all the following parameters, unless otherwise specified.)
 AC: VEE Range: -4.2V to -5.7V, LOADING: 25 Ohms to -2.0V, VCC=VCCA=GND

SYMBOL	PARAMETER	CONDITIONS	NOTES	PIN-NAME	MIN	MAX	UNIT	SUB-GROUPS
tpLH/tpHL(1)	Propagation Delay	VEE=-4.2/-5.7V	2, 4	Dn to Qn	0.5	2.4	ns	9
			2, 4	Dn to Qn	0.5	2.7	ns	10
			2, 4	Dn to Qn	0.3	2.6	ns	11
tpLH(2)	Propagation Delay	VEE=-4.2/-5.7V	2, 4	OEN to Qn	1.4	4.2	ns	9
			2, 4	OEN to Qn	1.2	4.4	ns	10, 11
tpHL(2)	Propagation Delay	VEE=-4.2/-5.7V	2, 4	OEN to Qn	0.7	2.8	ns	9
			2, 4	OEN to Qn	0.7	3.2	ns	10
			2, 4	OEN to Qn	0.7	3.0	ns	11
tTLH/tTHL	Transistion Time	VEE=-4.2/-5.7V	6	Qn	0.4	2.4	ns	9
			6	Qn	0.4	2.7	ns	10
			6	Qn	0.4	2.5	ns	11

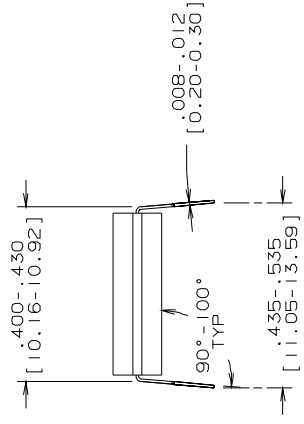
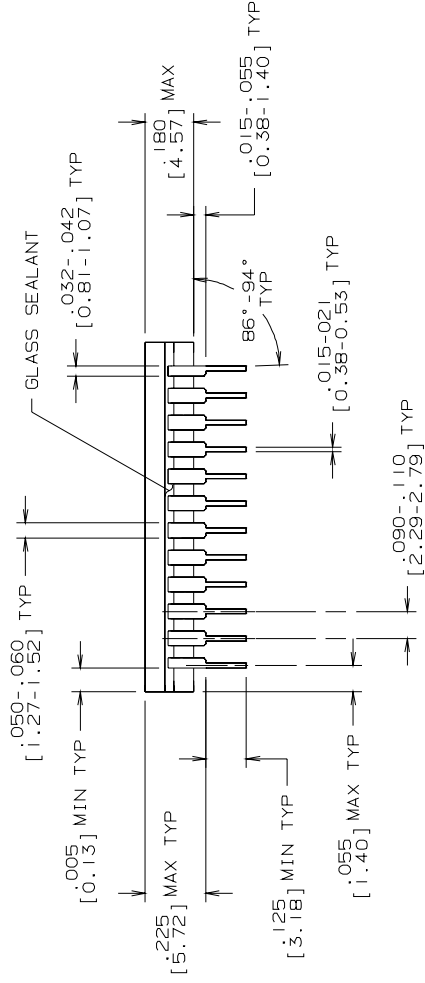
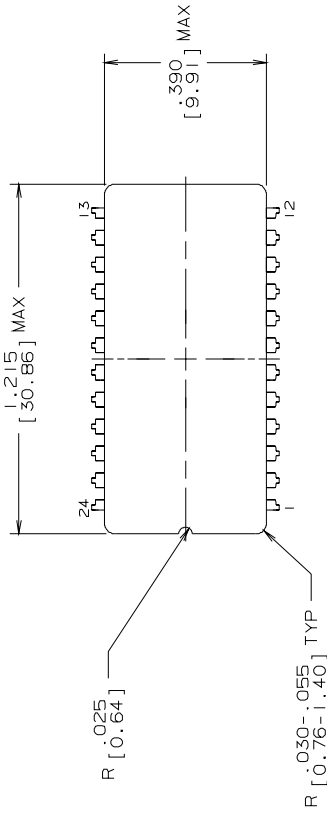
- Note 1: Screen tested 100% on each device at -55 C, +25 C and +125 C temp., subgroups 1, 2, 3, 7 & 8.
- Note 2: Screen tested 100% on each device at +25 C temp only, subgroup A9.
- Note 3: Sample tested (Method 5005, Table 1) on each MFG. lot at +25 C, +125 C & -55 C temp., subgroups A1, 2, 3, 7 & 8.
- Note 4: Sample tested (Method 5005, Table 1) on each MFG. lot at +25 C, subgroup A9, and at +125 C & -55 C temp., subgroups A10 & 11.
- Note 5: Sample tested (Method 5005, Table 1) on each MFG. lot at +25 C temp. only, subgroup A9.
- Note 6: Not tested at +25 C, +125 C & -55 C temp. (DESIGN CHARACTERIZATION DATA).
- Note 7: Guaranteed by applying specified input condition and testing VOH/VOL.

Graphics and Diagrams

GRAPHICS#	DESCRIPTION
J24ERJ	CERDIP (J), 24LD, .400 CENTERS (P/P DWG)
P000080A	CERDIP (J), 24LD .400 CENTERS (PIN OUT)
P000081A	CERPACK, QUAD, 24 LEAD (PIN OUT)
W24BRE	CERPACK, QUAD, 24 LEAD (P/P DWG)

See attached graphics following this page.

REVISIONS			
LTR	DESCRIPTION	E.C.N.	DATE
J	REVISE AND REDRAW	09044	03/05/92 DEG/



MIL/AERO MIL-M-38510 CONFIGURATION CONTROL CONFIGURATION CONTROL

CONTROLLING DIMENSION: INCH	
APPROVALS	DATE
DRAWN D.E. GRADY	03/05/92
DTG. CHK.	
ENGR. CHK.	
APPROVAL	
SCALE N/A	DRAWING NUMBER C
FORMERLY: N/A	MKT-J24E
SHEET 1	OF 1

NOTES: UNLESS OTHERWISE SPECIFIED

- LEAD FINISH: SOLDER DIPPED WITH Sn60 OR Sn63 SOLDER CONFORMING TO MIL-M-38510 TO A MINIMUM THICKNESS OF 200 MICRONS/5.08 MICROMETERS. SOLDER MAY BE APPLIED OVER LEAD BASIS METAL OR Sn PLATE.
- LEAD THICKNESS MAY BE INCREASED BY .003 [0.08] MAXIMUM AFTER LEAD FINISH APPLIED.
- BUMPERS ARE AVAILABLE ON CERTAIN PRODUCTS. BUMPERS WILL ADD .040 [1.02] MAX TO THE LENGTH OF THE PACKAGE.
- NO JEDEC REGISTRATION AS OF 2/17/92.

NATIONAL SEMICONDUCTOR CORPORATION
 2900 Semiconductor Drive, Santa Clara, CA 95052-8090
 CERDIP (J),
 24 LEAD,
 .400 CENTERS

Revision History

Rev	ECN #	Rel Date	Originator	Changes
1A0	M0002979	08/24/98	Donald B. Miller	1) Change page 5, tpLH(2) minimum limit for subgroup 9 from 1.2 ns to 1.4 ns. 2) Change page 5, tpLH(2) minimum limit for subgroups 10 & 11 from 1.4 ns to 1.2 ns.